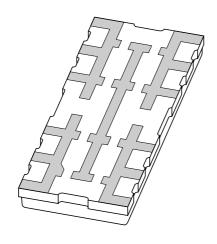
DISCRETE SEMICONDUCTORS

DATA SHEET



BGY282 dual band UHF amplifier module for GSM900 and GSM1800

Preliminary specification

2001 Dec 04





dual band UHF amplifier module for GSM900 and GSM1800 BGY282

FEATURES

- Dual band GSM amplifier
- 3.5 V nominal supply voltage
- 33 dBm output power for GSM1800
- 35 dBm output power for GSM900
- Easy output power control by DC voltage
- · Internal input and output matching
- Easy band selection by DC voltage
- Suited for GPRS class 12 (duty cycle 4:8).

APPLICATIONS

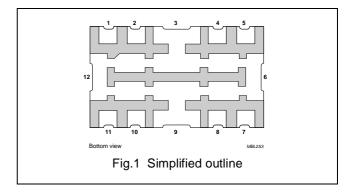
 Digital cellular radio systems with Time Division Multiple Access (TDMA) operation (GSM systems) in two frequency bands: 880 to 915 MHz and 1710 to 1785 MHz.

DESCRIPTION

The BGY282 is a power amplifier module in a SOT632A surface mounted ceramic package with a plastic cap. The module consists of two separated line-ups, one for GSM900 and one for GSM1800 with internal power control, input and output matching.

PINNING - SOT632A

PIN	DESCRIPTION
1	RF input 1 (GSM900)
2	V _{APC}
3, 6, 9, 12	Ground
4	V _{S1} (GSM900)
5	RF output 1 (GSM900)
7	RF output 2 (GSM1800)
8	V _{S2} (GSM1800)
10	V_{band}
11	RF input 2 (GSM1800)



QUICK REFERENCE DATA

RF performance at $T_{mb} = 25$ °C.

MODE OF OPERATION	f (MHz)	V _S (V)	V _{APC} (V)	P _L (dBm)	η (%)	Z _S , Z _L (Ω)
Pulsed; $\delta = 1:8$	880 to 915	3.5	≤2.2	typ. 35	50	50
Fuiseu, 0 = 1.0	1710 to 1785	3.5	≤2.2	typ. 33	45	50

dual band UHF amplifier module for GSM900 and GSM1800

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V V	DC aumply weltage	$V_{APC} = 0$; $RF_{IN} = off$	_	7	V
V_{S1}, V_{S2}	DC supply voltage	$V_{APC} > 0.5 \text{ V}; RF_{IN} = \text{on}$	_	5.5	V
V _{APC}	DC control voltage		_	3	V
P _{D1} , P _{D2}	input drive power		_	10	dBm
P _{L1}	load power 1 (GSM900)		_	36	dBm
P _{L1}	load power 1 (GSM900)	$\delta = 4 : 8; VSWR_{out} > 2 : 1$	_	35	dBm
P _{L2}	load power 2 (GSM1800)		_	35	dBm
P _{L2}	load power 2 (GSM1800)	$\delta = 4 : 8; VSWR_{out} > 2 : 1$	_	34	dBm
P _{S1}	total power from supply during pulse (GSM900)	δ = 4:8	_	7.5	W
P _{S2}	total power from supply during pulse (GSM1800)	δ = 4:8	_	4.5	W
T _{stg}	storage temperature		-40	+100	°C
T_{mb}	operating mounting base temperature		-30	+90	°C

Note: P_L is forward power, measured in a coupler.

dual band UHF amplifier module for GSM900 and GSM1800

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CHARACTERISTICS

 $Z_S=Z_L=50~\Omega;~P_{D1,2}=0~dBm;~V_{S1}=V_{S2}=3.5~V;~V_{APC}\leq 2.2~V;~T_{mb}=25~^{\circ}C;~t_p=575~\mu s;~\delta=1:8;~f=880~to~915~MHz~(GSM900);~f=1710~to~1785~MHz~(GSM1800);~measured~on~demoboard~of~fig~7;~unless~otherwise~specified.$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{band}	band switch voltage	GSM1800 selected	0	_	0.7	V
		GSM900 selected	1.7	_	5.5	V
I _{band}	band switch current		_	_	30	μΑ
IL	leakage current	V _{APC} = 0.2 V; P _{D1,2} = 0 mW	_	_	10	μΑ
I _{CM1} , I _{CM2}	peak control current		_	_	2	mA
P _{D1}	input drive power (GSM900)		-3	_	4	dBm
P _{D2}	input drive power (GSM1800)		-3	2	5	dBm
D	lood nower CCM000	V _{APC} = 2.2 V	34.7	35	_	dBm
P_{L1}	load power GSM900	V _{APC} = 2.2 V; V _{S1} = 3.1 V	34.2	34.5	_	dBm
Б	land names COMMOOO	V _{APC} = 2.2 V	32.3	33	_	dBm
P_{L2}	load power GSM1800	V _{APC} = 2.2 V; V _{S1} = 3.1 V	31.7	32.3	_	dBm
η_1	efficiency GSM900	V _{APC} = 2 V	43	50	_	%
η ₂	efficiency GSM1800	V _{APC} = 2 V	38	45	_	%
	harmonics GSM900	P _{L1} = 34.7 dBm	_	_	-38	dBc
H_2 , H_3	harmonics GSM1800	P _{L2} = 32.3 dBm	_	_	-35	dBc
VSWR _{in}	input VSWR of active device	$V_{S1,2} = 3.1 \text{ to } 4.4 \text{ V}; P_{D1,2} = 0 \text{ dBm};$ $P_{L1} = 5 \text{ to } 34.7 \text{ dBm};$ $P_{L2} = 0 \text{ to } 32.3 \text{ dBm}$	_		3:1	
	input VSWR of inactive device	$V_{S1,2} = 3.1 \text{ to } 5.15 \text{ V}; V_{APC} \le 0.5 \text{ V}$	_		8:1	
		$V_{S1,2} = 3 \text{ to } 5 \text{ V}; P_{D1} = 0 \text{ to } 3 \text{ dBm};$ $P_{D2} = 0 \text{ to } 5 \text{ dBm}; P_{L1} = <35 \text{ dBm};$ $P_{L2} = <33 \text{ dBm}; VSWR = 6 : 1 \text{ through}$ all phases	_	_	-60	dBc
	stability	$V_{S1,2} = 3.1$ to 4.2 V; $P_{D1} = 0$ to 3 dBm; $P_{D2} = 0$ to 5 dBm; $P_{L1} = <34$ dBm; $P_{L2} = <32$ dBm; VSWR = 6 : 1 through all phases; $\delta = 4$: 8	_	_	-60	dBc
	isolation	$V_{APC} = 0.5 \text{ V}; P_{D1} = 3 \text{ dBm};$ $P_{D2} = 5 \text{ dBm}$	-	-	-36	dBm
	second harmonic isolation from GSM900 into GSM1800	P _{L1} = 34.7 dBm	_	_	-20	dBm
	maximum control slope	-5 dBm < P _{L1,2} < P _{L max}	120	_	200	dB/V
t _r	carrier rise time	P_{L1} = 5 to 34 dBm; P_{L2} = 0 to 32 dBm; time to settle within –0.5 dB of final P_L	-	1.5	2	μs
t _f	carrier fall time	P_{L1} = 5 to 34 dBm; P_{L2} = 0 to 32 dBm; time to settle within –0.5 dB of final P_{L}	_	1.5	2	μs

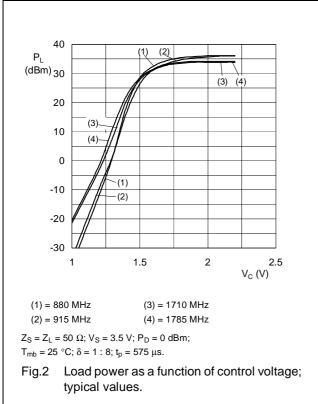
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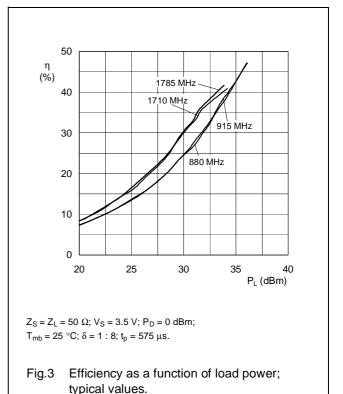
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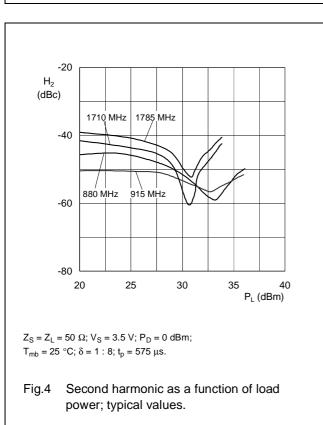
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
	naina nawar CSM000	$P_{L1} \le 34$ dBm; bandwidth = 100 kHz; $f = 925$ MHz	-	-	-7 1	dBm
P _n	noise power GSM900	$P_{L1} \le 34$ dBm; bandwidth = 100 kHz; $f = 935$ MHz	_	_	-80	dBm
	noise power GSM1800	$P_{L2} \le 32 \text{ dBm}$; bandwidth = 100 kHz; $f = 1805 \text{ MHz}$		_	-76	dBm
	AM/PM conversion	$P_{D1,2} = -0.5$ to 0.5 dBm; $P_{L1} = 5$ to 34 dBm; $P_{L2} = 0$ to 32 dBm; $P_{L1,2} = constant during measurement$	-	_	6	deg/dB
	AM/AM conversion	P _{D1,2} = 4 %; f = 100 kHz; P _{L1} = 5 to 34.7 dBm; P _{L2} = 0 to 32.3 dBm	-	-	30	%
CG	conversion gain GSM900	$P_{D1} = 0 \text{ dBm } @ 915 \text{ MHz};$ $P_{L1} = 34 \text{ dBm};$ $P_{i1} = -50 \text{ dBm } @ 905 \text{ MHz};$ $CG = P_{925} - P_{i1}$	_	25	_	dB
CG	conversion gain GSM1800	$P_{D2} = 0 \text{ dBm } @ 1785 \text{ MHz};$ $P_{L2} = 32 \text{ dBm};$ $P_{i2} = -50 \text{ dBm } @ 1765 \text{ MHz};$ $CG = P_{1805} - P_{i2}$	_	25	_	dB
	3 dB control bandwidth GSM900, GSM1800	$P_{L1} = 5 \text{ to } 34 \text{ dBm}; P_{L2} = 0 \text{ to } 32 \text{ dBm}$	0.5	_	-	MHz
	power drop 4 slot burst GSM900, GSM1800	V_{APC} = 2.2 V; difference P_L with δ = 1 : 8 and δ = 4 : 8	_	_	0.4	dB
		$V_{S1,2} = 5 \text{ V}; P_{D1} = 0 \text{ to } 3 \text{ dBm};$ $P_{D2} = 0 \text{ to } 5 \text{ dBm}; P_{L1} = <35 \text{ dBm};$ $P_{L2} = <33 \text{ dBm}; VSWR \le 6:1 \text{ through}$ all phases	no degradation			
	ruggedness	$V_{S1,2} = 4.2 \text{ V; } P_{D1} = 0 \text{ to } 3 \text{ dBm;}$ $P_{D2} = 0 \text{ to } 5 \text{ dBm; } P_{L1} = <35 \text{ dBm;}$ $P_{L2} = <33 \text{ dBm; } VSWR \le 10 : 1$ through all phases	no degradation			
		$V_{S1,2} = 4.2 \text{ V; } P_{D1} = 0 \text{ to } 3 \text{ dBm;}$ $P_{D2} = 0 \text{ to } 5 \text{ dBm } P_{L1} = <34 \text{ dBm;}$ $P_{L2} = <32 \text{ dBm; } VSWR \le 6:1 \text{ through}$ all phases; $\delta = 4:8$	no degradation			

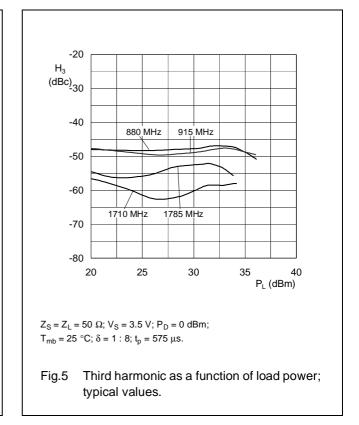
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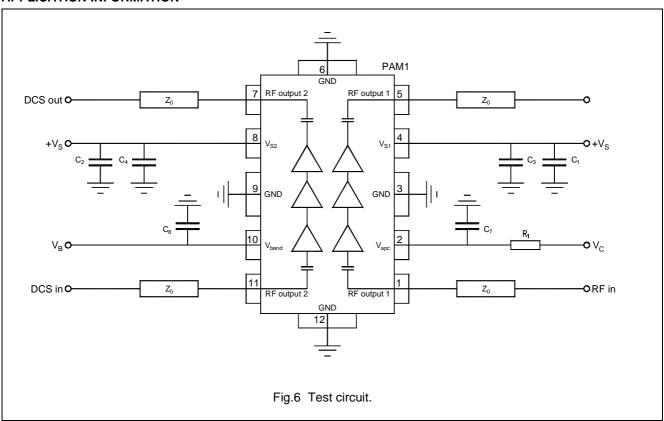




dual band UHF amplifier module for GSM900 and GSM1800

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APPLICATION INFORMATION



List of components

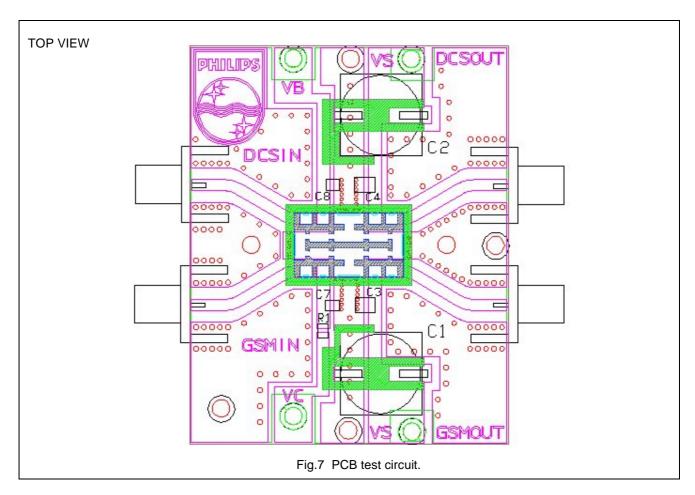
QUANTITY	LOCATION	VALUE / TYPE	DESCRIPTION	REMARK	SUPPLIER
1			PCB		Roland Haefele
1	PAM1	BGY282	Power amplifier module		
4			Jack assembly end launch SMA connector	Type no. 142-0701-881	Johnson Components
1	C1	100 μF / 35 V	Electrol. capacitor	Type no. ECEV1VA101P	Matsushita
1	C2	100 μF / 35 V	Electrol. capacitor	Type no. ECEV1VA101P	Matsushita
1	C3	100 nF	0805 size SMD capacitor		
1	C4	100 nF	0805 size SMD capacitor		
1	C7	680 pF	0603 size SMD capacitor		
1	C8	100 pF	0603 size SMD capacitor		
1	R1	100 Ohms / 0.1 W	0805 size SMD resistor		
4	Z0	50 Ω	stripline; note 1	width 1.4 mm	

Note

1. The striplines are on a double etched printed circuit board ($\varepsilon_r = 4.6$); thickness 0.8 mm

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SOLDERING

The indicated temperatures are those at the solder interfaces.

Advised solder types are types with a liquidus less or equal to 210 $^{\circ}\text{C}$.

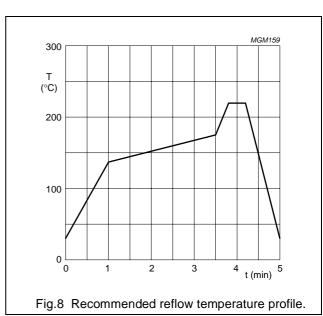
Soldering can be carried out using a conveyor oven, a hot air oven, an infrared oven or a combination of these ovens. A double reflow process can be used.

Hand soldering is not recommended because of the nature of the contacts.

The maximum allowed temperature is 250 $^{\circ}$ C for a maximum of 5 seconds.

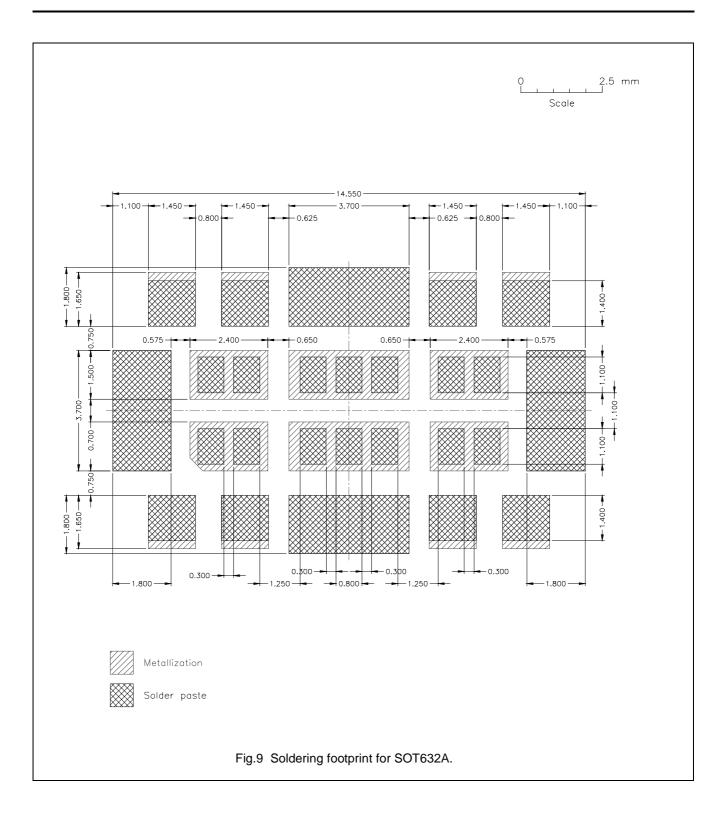
The maximum ramp-up is 10 °C per second.

The maximum cool-down is 5 °C per second.



dual band UHF amplifier module for GSM900 and GSM1800

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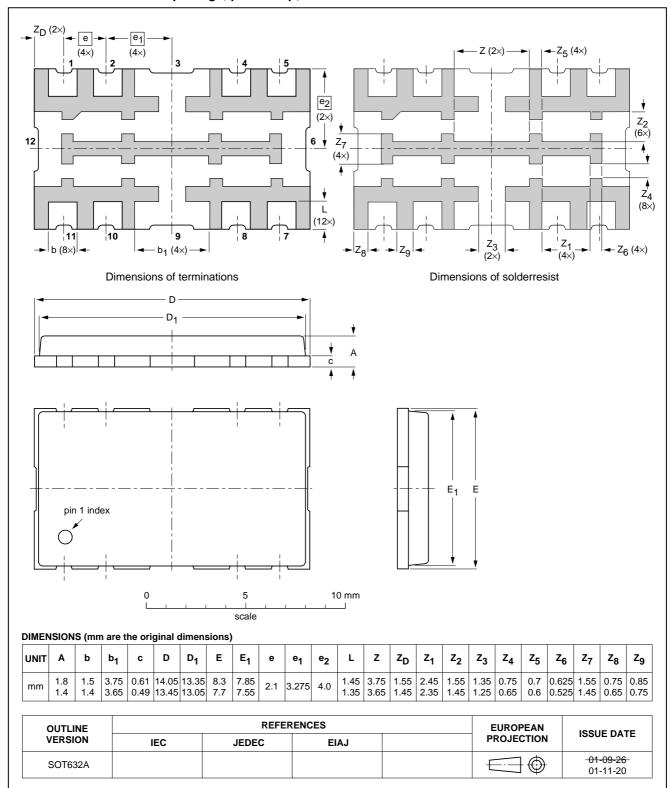
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PACKAGE OUTLINE

Leadless surface mounted package; plastic cap; 12 terminations

SOT632A



dual band UHF amplifier module for GSM900 and GSM1800

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DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
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Notes

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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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